# How to correctly simulate with the SPS impedance model?

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Acknowledgements: D. Quartullo, J. Repond, BLonD dev team



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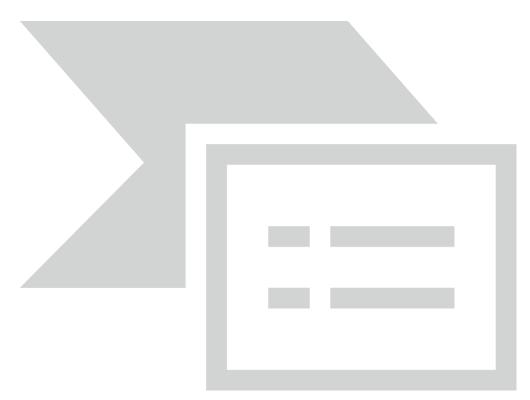
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### Content

- SPS impedance model
- RF fast-sine vs rf-kick-interp

### Present SPS impedance model

- 1 travelling wave object (800 MHz)
- 230 resonators (max fr: 8.5GHz, min bw 94kHz)
- 2 impedance tables
  - Resistive\_wall.dat (up to 100GHz, logarithmic spacing)
  - totWrongZSME\_imp.dat (up to 5GHz with 166kHz frequency spacing)



#### Basic discrete Fourier transform stuff

- N data points at times  $t_n = n \Delta t$  with  $n = 0 \dots N 1$
- $t_{max} = (N-1)\Delta t, t_{period} = N\Delta t$
- Maximum (Nyquist) frequency  $f_c = \pm 1/2\Delta t$ ,  $\Delta f = 1/N\Delta t$

Press et al., Numerical Recipes, 3<sup>rd</sup> ed

# Induced voltage

$$V_{ind}(t) = \int \lambda(t-\tau)w(\tau)d\tau = Re \int_0^\infty Z(\omega)\lambda(\omega)d\omega$$

- In BLonD different objects to compute V<sub>ind</sub>:
  - InducedVoltageFreq (uses given impedance  $Z(\omega)$ )
  - InducedVoltageTime (uses given wake  $w(\tau)$ , computes convolution via frequency domain)
  - InducedVotlageResonator (only for resonators, uses semi-analytic method)
- Maximum frequency determined by profile.bin\_size (corresponds to  $\Delta t$ )
- Frequency resolution  $\Delta f$  determined dynamically

Which method to chose?

Some considerations (mainly for resonators):

- Bunch lengths on the order of 5ns -> 200 MHz
- With 64 bins per RF-bucket, Nyquist frequency ~ 6GHz
- To resolve a resonator, need frequency spacing < band width (otherwise front wake);</li>
  impedance model suggests Δf < 90kHz (2 f\_rev = 86kHz)</li>
- My criterion:

If resonator is broad-band (bandwidth >>  $\Delta f$ ) and low-frequency part important (1  $\ll \omega_r \sigma$ ) -> chose frequency domain, otherwise time domain

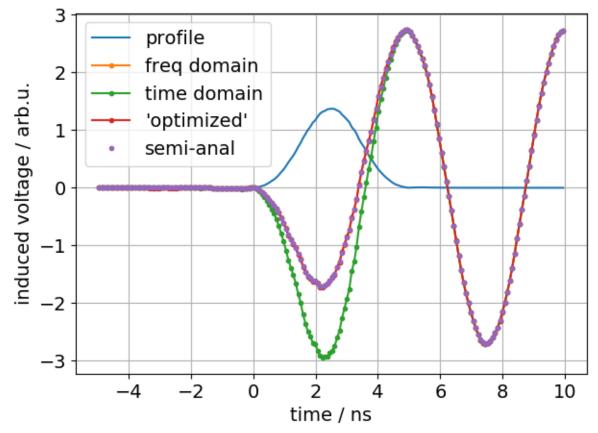
#### Induced voltage, example Gaussian bunch



Compute V\_ind (resonators only) from impedance model using

- all resonators with InducedVoltageFreq (orange)
- all resonators with InducedVoltageTime (green)
- Optimize by applying criterion from last slide (red)
- Semi-analytic method (purple)
  With 64 bins per RF-bucket

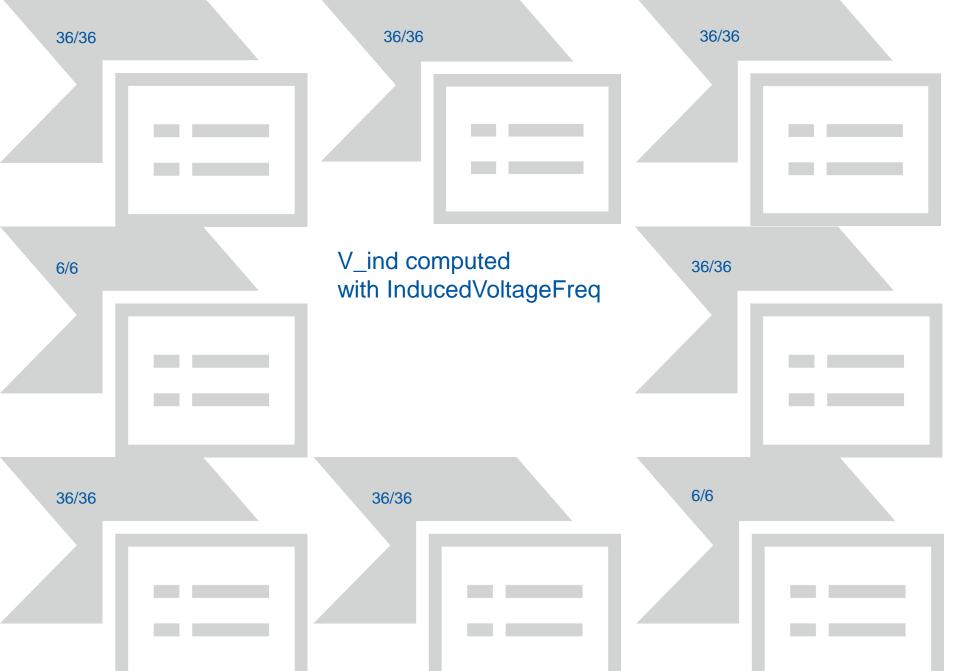
# Induced voltage, example Gaussian bunch



Timings:

- Frequency: 8 ms
- Time: 84 micro s (135 micro s for 256 bins per RF-buckets)
- Optimized: 127 micro s
- Semi-analytic: 62 micro s

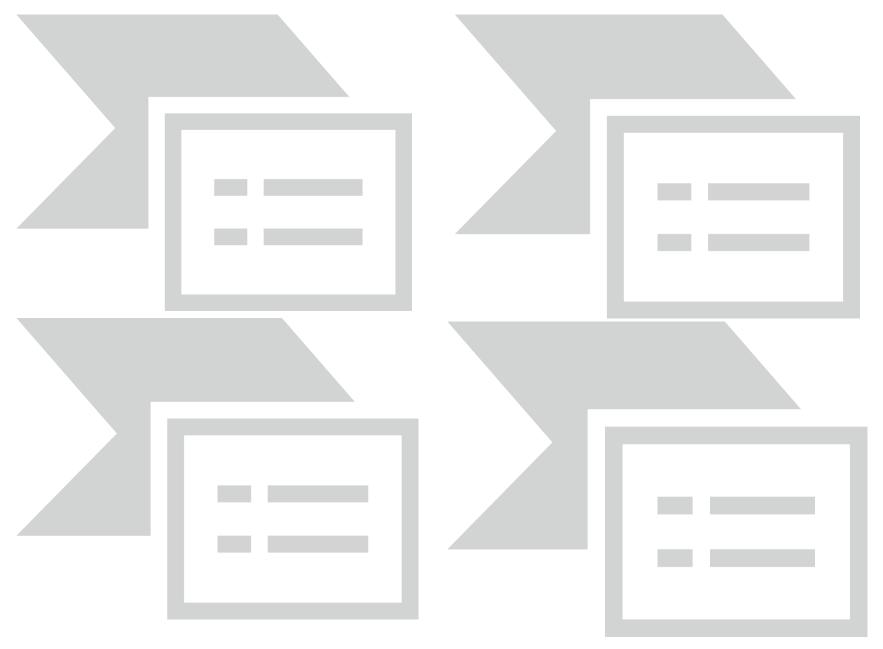
#### Example scanning bins/RF-bucket, df, #macro-particles



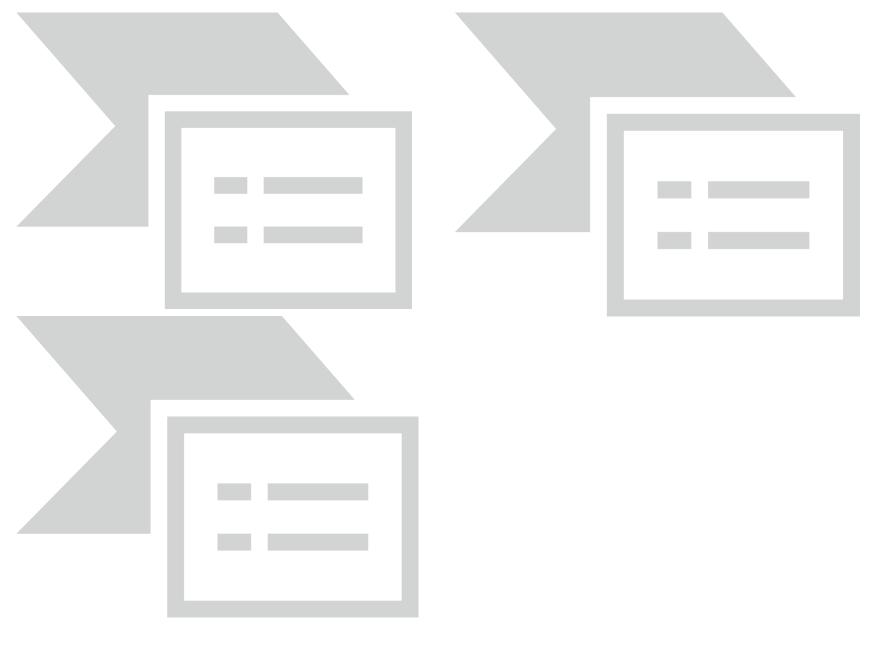
### Convergence rf\_kick\_interp vs fast\_sine

- With same initial distribution:
- run n turns using fast\_sine -> keep this as reference
- run n turns using rf\_kick\_interp -> vary bins/RF-bucket
- Compute  $\chi^2 = \sum_{macroparticles} (refbeam. dt beam. dt)^2$
- Similar for energies of particles

#### Convergence rf\_kick\_interp vs fast\_sine: **10k** macroparticles



#### Convergence rf\_kick\_interp vs fast\_sine: 1M macroparticles



#### Runtime rf\_kick\_interp vs fast\_sine

